TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4017AP,TC74HC4017AF

Decade Counter/Divider

The TC74HC4017A is a high speed CMOS DECADE JOHNSON COUNTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaing the CMOS low power dissipation.

It contains 5-stage divided-by-10 Johnson counter with 10 decoded output (Q0-Q9) and carry-out bit.

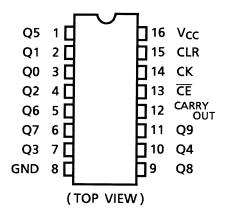
This counter is advanced on the positive edge of clock signal when clock enable signal (\overline{CE}) input is held low, or it is advanced on the negative edge of the \overline{CE} when CK input is held high, and selected one of ten outputs goes high. Holding high the CLR input, this counter is cleared to its zero state without regard to the other input conditions.

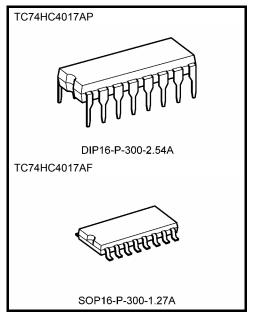
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 87 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Outputs drive capability: 10 LSTTL loads
- Symmetrical output impedance: | I_{OH} | = I_{OL} = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2~6 V
- Pin and function compatible with 4017B

Pin Assignment

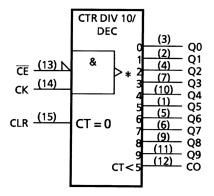




Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.)

IEC Logic symbol

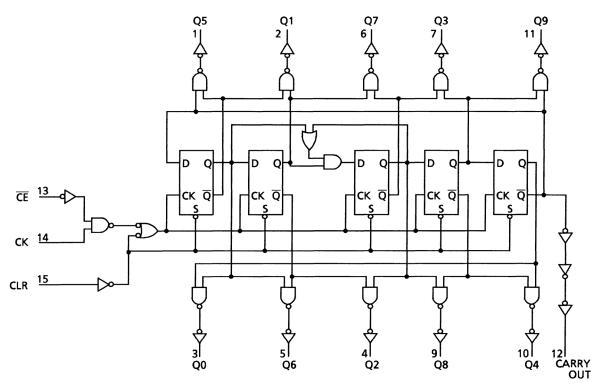


Truth Table

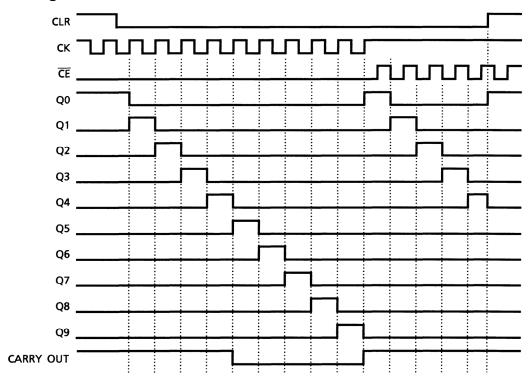
	Inputs		Decode Output (H)				
CK	CE	CLR	Decode Output (H)				
Х	Х	Н	Q0				
L	Х	L	Qn				
Х	Н	L	Qn				
	L	L	Qn + 1				
\neg	L	L	Qn				
Н		L	Qn				
Н	\Box	L	Qn + 1				

X: Don't care

System Diagram



Timing Chart



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	٧
Input diode current	l _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	−65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

3



Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	٧
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

		Test Condition		Ta = 25°C			Ta = -40~85°C			
Characteristics	Symbol				Min	Тур.	Max	Min	Max	Unit
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
Ğ				6.0	4.20		_	4.20		
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_		4.5	_		1.35	_	1.35	V
Ğ				6.0	_		1.80	_	1.80	
	Voн	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9		
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9		V
			I _{OH} = -4 mA	4.5	4.18	4.31	_	4.13		
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IH} or		2.0	_	0.0	0.1	_	0.1	
			I _{OL} = 20 μA	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
		V _{IL}	I _{OL} = 4 mA	4 mA 4.5 — 0.17 0.26	_	0.33				
			I _{OL} = 5.2 mA	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0			±0.1	_	±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{C}$	_C or GND	6.0	_	_	4.0	_	40.0	μА



Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 ~85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	mit	
Minimum pulse width	tu a		2.0	_	75	95		
(CK)	t _{W (L)}	_	4.5	_	15	19	ns	
(CK)	t _{W (H)}		6.0	_	13	16		
Minimum pulse width			2.0	_	75	95		
(CLR)	t _{W (H)}	_	4.5	_	15	19	ns	
(CLK)			6.0	_	13	16		
			2.0	_	50	60		
Minimum set-up time	ts	_	4.5	_	10	12	ns	
			6.0	_	9	11		
			2.0	_	75	95		
Minimum hold time	t _h	_	4.5	_	15	19	ns	
			6.0	_	13	16		
Minimum removal time			2.0	_	50	60		
(CLR)	t _{rem}	_	4.5	_	10	12	ns	
(CLR)			6.0	_	9	11		
			2.0	_	5	4		
Clock frequency	f	_	4.5	_	25	20	MHz	
			6.0	_	29	25		

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25 ^{\circ}\text{C}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	haracteristics Symbol Test Condition		Min	Тур.	Max	Unit
Output transition time	t _{TLH}	_	_	6	12	ns
Propagation delay time	t _{pLH}	_		21	34	ns
(CK, CE -Q, CARRY)	t _{pHL}					110
Propagation delay time	t_{pLH}			19	30	ns
(CLR-Q, CARRY)	t_{pHL}	_	_	19	30	115
Maximum clock frequency	f _{max}		29	87	_	MHz

5



AC Characteristics ($C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

		Test Condition		-	Ta = 25°C			Ta = -40~85°C		
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
	t		2.0	_	30	75	_	95		
Output transition time	t _{TLH}	_	4.5	_	8	15	_	19	ns	
	t _{THL}		6.0	_	7	13	_	16		
Propagation delay	4		2.0	_	85	195	_	440		
time	t _{pLH}	_	4.5	_	25	39	_	88	ns	
(CK, $\overline{\text{CE}}$ -Q, CARRY)	t _{pHL}		6.0	_	20	33	_	75		
Propagation delay	4		2.0	_	75	175	_	375		
time	t _{pLH}	_	4.5	_	22	35	_	75	ns	
(CLR-Q, CARRY)	t _{pHL}		6.0	_	18	30	_	64		
			2.0	5	18	_	4	_		
Maximum clock frequency	f _{max}	_	4.5	25	68	_	20	_	MHz	
in equality			6.0	29	90	_	24	_		
Input capacitance	C _{IN}	_	_	_	5	10	_	10	pF	
Power dissipation	C _{PD}		_		38				pF	
capacitance	(Note)				36				μΓ	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

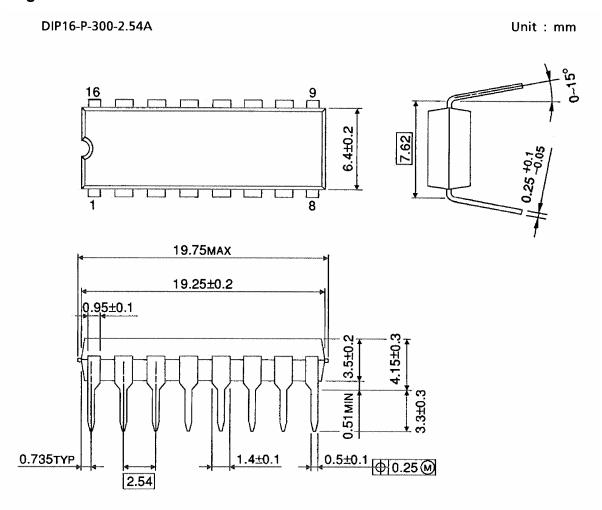
6

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$



Package Dimensions

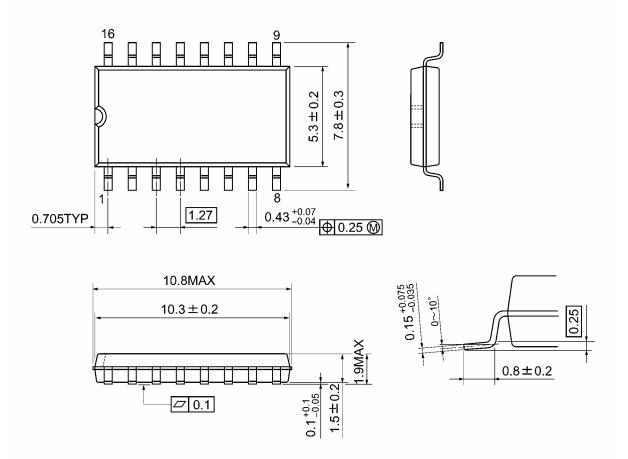


Weight: 1.00 g (typ.)



Package Dimensions

SOP16-P-300-1.27A Unit: mm



8

Weight: 0.18 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
 compatibility. Please use these products in this document in compliance with all applicable laws and regulations
 that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
 occurring as a result of noncompliance with applicable laws and regulations.